

20A 400V Fast recovery diode

1 Description

20A, 400V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

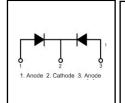
TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

2 Features

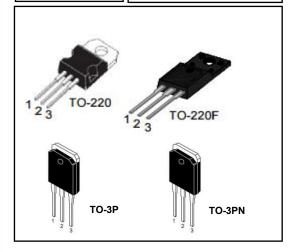
- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose



 $V_{BR} = 400V$ $V_{F}(\text{single}) = 1.4V$ $I_{F(AV)}(\text{single}) = 10A$



4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25 °C, unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		V _{RRM}	400	٧
Working Peak Reverse Voltage		V_{RWM}	400	V
DC Blocking Voltage		V_R	400	V
Average Rectified Forward Current(single)	Tc=135℃		10	Α
Average Rectified Forward Current(double) T _C =135 ℃		l _{F(AV)}	20	Α
Repetitive Peak Surge Current(single)		I _{FRM}	15	Α
Nonrepetitive Peak Surge Current(single) t _p =8.3ms		I _{FSM}	120	Α
Avalanche Energy(single) L=1mH		E _{AS}	15	mJ
Operating Junction Temperature Range		Tj	-55∼150	$^{\circ}$ C
Storage Temperature Range		T _{stg}	-55∼150	$^{\circ}$

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE			UNIT
PARAWETER	STWIDGE	TO-220F	TO-220	TO-3P	UNIT
Thermal Resistance, Junction to Case-sink	R _{thJC}	2.5	1.8	0.8	°C/W



4.3 Electrical Characteristics

(Tc=25[°]C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	V _F	I _F =10A	-	1.15	1.4	V
Forward Voltage		I _F =10A, T _C = 150°C	-	-	1.25	V
		I _F = 15A	-	1.21	1.5	V
Maximum Instantaneous	I _R	V _R = 400V	-	-	5	uA
Reverse		V _R = 400V, TC = 150°C	-	-	1	mA
Maximum Reverse	trr	V _R =30V IF=1A -dI/dt=50A/us	-	26	35	ns
Recovery Time						
Total capacitance	C _{tot}	V _R =0V f=1MHz	-	155	-	pF
DC Blocking Voltage	V_{BR}	I _R =100uA	410	440	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

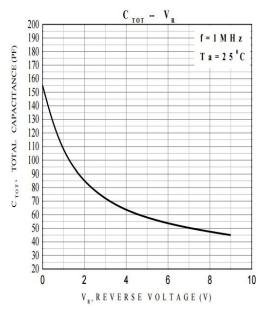


FIGURE 1. Total capacitance vs Voltage

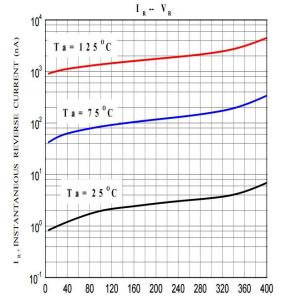


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



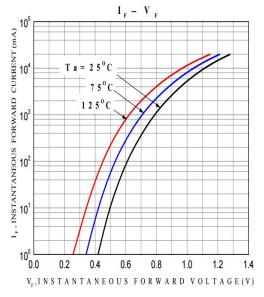


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

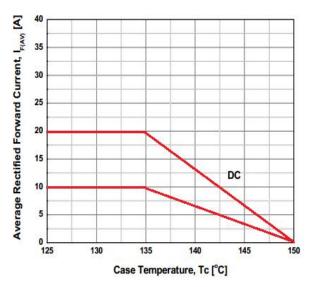


FIGURE 4. CURRENT DERATING CURVE

6 Typical Test Circuit and Waveform

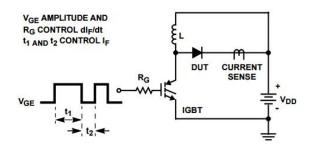


FIGURE 5. trr TEST CIRCUIT

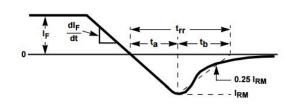


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

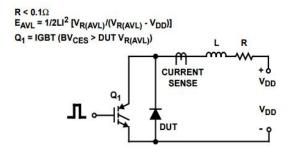


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

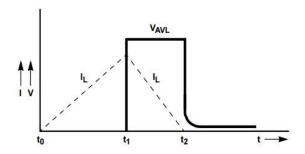
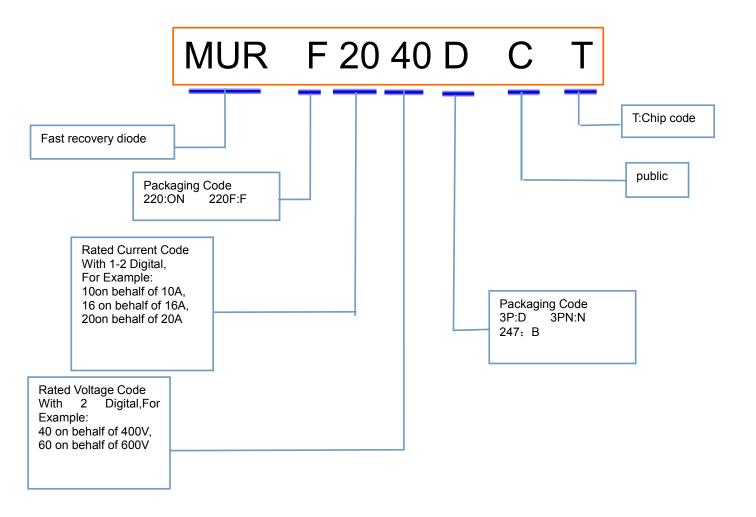


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Names Rules



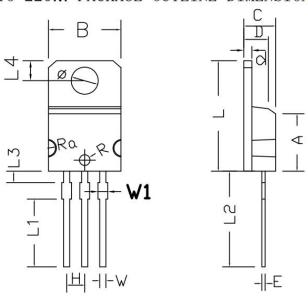
8 Product Specifications and Packaging Models

Р	roduct Model	Package Type	Mark Name	RoHS	Package	Quantity
N	MUR2040CT	TO-220	MUR2040CT	Pb-free	Tube	1000/box
IV	IURF2040CT	TO-220F	MURF2040CT	Pb-free	Tube	1000/box
M	IUR2040DCT	TO-3P	MUR2040DCT	Pb-free	Tube	300/box
M	IUR2040NCT	TO-3PN	MUR2040NCT	Pb-free	Tube	300/box



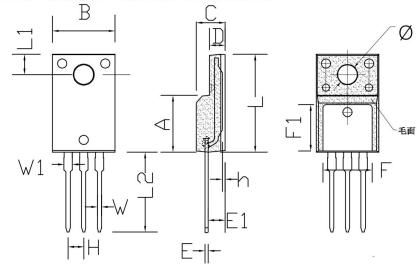
9 Dimensions

TO-220M PACKAGE OUTLINE DIMENSIONS



Comba 1	Dimensions	In Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
	MIN	MAX	MIN	MAX
A	8.03	8. 05	0. 316	0.317
В	10. 13	10. 23	0.399	0. 403
С	4. 42	4. 52	0. 174	0. 178
D	3. 42	3. 52	0. 135	0. 139
Е	0.44	0.46	0.017	0.018
L	15. 25	15. 45	0.601	0.609
Н	2. 52	2.56	0.099	0. 101
W	0.85	0.87	0.033	0.034
Φ	3. 78	3.82	0. 149	0. 151
R	0.74	0.76	0.029	0.030
Ra	9.44	9.48	0. 372	0. 374
d	1.28	1.32	0.050	0.052
L1	9. 4	9.6	0.370	0.378
L2	13. 22	13. 62	0. 521	0. 537
L3	1. 52	1.72	0.060	0.068
L4	2.7	2.9	0. 106	0. 114
W 1	1, 32	1.42	0. 052	0, 056

TO-220F PACKAGE OUTLINE DIMENSIONS

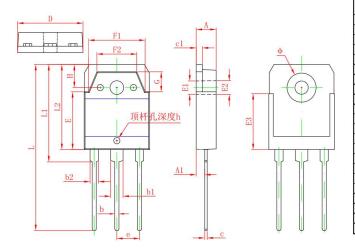


	D	1.42112	D: .	The Table 1
Symbol	DimensionsIn	Millimeters	Dimensions	sin inches
Syllibol	min.	max.	min.	max.
А	8.80	9.30	0.346	0.366
В	10.00	10.50	0.394	0.413
С	4.30	4.90	0.169	0.193
D	2.30	2.70	0.091	0.106
L	15.55	16.15	0.612	0.636
h	0.40	0.60	0.016	0.024
L1	3.15	3.55	0.124	0.140
L2	12.65	13.35	0.498	0.526
W	0.70	0.90	0.028	0.035
W1	1.15	1.55	0.045	0.061
Н	2.54	TYP	0.100 TYP	
E	0.48	0.53	0.019	0.021
ф	2.90	3.40	0.114	0.134
E1	2.40	2.90	0.094	0.114
F	7.75	8.25	0.305	0.325
F1	7.35	7.85	0.289	0.309



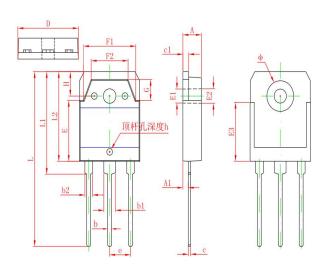


TO-3PN PACKAGE OUTLINE DIMENSIONS



C b - 1	Dimensions In Millimeters		D im en sion	s In Inches	
Symbol	M in	Max	M in	Max	
Α	4.600	5.000	0.181	0.197	
A 1	2.200	2.600	0.087	0.102	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200 REF		0.126 REF		
E 2	3.300 REF		0.130	0.130 REF	
E 3	13.450	REF	0.530 REF		
F1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.450	TYP	0.21	TYP	
Н	5.000	REF	0.197	7 REF	
h	0.000	0.300	0.000	0.012	

TO-3P PACKAGE OUTLINE DIMENSIONS



C.u.m.b.a.l	Dimensions In Millimeters		Dimension	s In Inches
Symbol	M in	Max	Min	Max
Α	4.600	5.000	0.181	0.197
A 1	1.200	1.600	0.047	0.063
b	0.800	1.200	0.031	0.047
b 1	2.800	3.200	0.110	0.126
b 2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.450	1.650	0.057	0.065
D	15.450	15.850	0.608	0.624
E	13.700	14.100	0.539	0.555
E 1	3.200 REF		0.126	REF
E 2	3.300 REF		0.130 REF	
E 3	13.450 REF		0.530	REF
F1	13.400	13.800	0.528	0.543
F2	9.400	9.800	0.370	0.386
L	39.900	40.300	1.571	1.587
L1	23.200	23.600	0.913	0.929
L2	20.300	20.600	0.799	0.811
Φ	6.900	7.100	0.272	0.280
G	5.150	5.550	0.203	0.219
е	5.45	0 TYP	0.215 TYP	
Н	5.00	0 REF	0.197 REF	
h	0.000	0.300	0.000	0.012



10 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

Date	REV.	Description	Page
2017.07.22	1.0	Original	